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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/761,704	01/21/2004	Tingkai Li	SLA 0845	3680
27518	7590	06/30/2005	EXAMINER	
DAVID C RIPMA, PATENT COUNSEL SHARP LABORATORIES OF AMERICA 5750 NW PACIFIC RIM BLVD CAMSAS, WA 98607				ERDEM, FAZLI
ART UNIT		PAPER NUMBER		
		2826		

DATE MAILED: 06/30/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

Gm

Office Action Summary	Application No.	Applicant(s)	
	10/761,704	LI ET AL.	
	Examiner Fazli Erdem	Art Unit 2826	

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

1) Responsive to communication(s) filed on 13 April 2005.

2a) This action is FINAL. 2b) This action is non-final.

3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

4) Claim(s) 1,4-9,11-13,16-21 and 23 is/are pending in the application.

4a) Of the above claim(s) _____ is/are withdrawn from consideration.

5) Claim(s) 4-8,11,12 and 16-20 is/are allowed.

6) Claim(s) 1,9,13 and 21 is/are rejected.

7) Claim(s) 23 is/are objected to.

8) Claim(s) _____ are subject to restriction and/or election requirement.

Application Papers

9) The specification is objected to by the Examiner.

10) The drawing(s) filed on _____ is/are: a) accepted or b) objected to by the Examiner.
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).

11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

Priority under 35 U.S.C. § 119

12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).

a) All b) Some * c) None of:

1. Certified copies of the priority documents have been received.

2. Certified copies of the priority documents have been received in Application No. _____.

3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

* See the attached detailed Office action for a list of the certified copies not received.

Attachment(s)

1) Notice of References Cited (PTO-892)

2) Notice of Draftsperson's Patent Drawing Review (PTO-948)

3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08)
Paper No(s)/Mail Date _____.

4) Interview Summary (PTO-413)
Paper No(s)/Mail Date. _____.

5) Notice of Informal Patent Application (PTO-152)

6) Other: _____.

DETAILED ACTION

Allowable Subject Matter

1. Claims 4-8, 11, 12, 16-20 allowed.
2. Claim 23 objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

3. Claims 1, 9, 13 and 21 rejected under 35 U.S.C. 103(a) as being unpatentable over Kim et al. (6,621,114) in view of Currie et al. (2003/0234439) further in view of Sohn et al. (6,753,230) further in view of Hoffman et al. (2004/0155846) further in view of Rotondaro et al. (6,656,852)

Regarding Claims 1, 9, 13 and 21, Kim et al. disclose MOS transistors with High-K dielectric gate insulator for reducing remote scattering where in Fig. 3, it is disclosed a MOS transistor 200 with source region 109, drain region 112, channel region 201 between the source/drain regions, High-K dielectric layer 208 over channel region 201 and gate electrode 118 overlying the High-K dielectric layer. Kim et al. fail to disclose the required surface channel, the required ultra-shallow channel structures, the required type of metal oxides and the required high-k dielectric thickness. However, Currie et al. disclose SiGe gate electrodes on SiGe substrate and methods of making the same where

in paragraph 30 the required surface channel structure is disclosed. Furthermore, Sohn et al. disclose a method for fabricating semiconductor device with ultra-shallow super-steep-retrograde epi-channel by decaborane doping where in Fig. 6E the required ultra shallow channel is disclosed. Hoffman et al. disclose transparent active matrix display where in Figs 10A-10B and paragraphs 28, 30, 42, 48 and 49, the required metal oxide is disclosed. Finally, Rotondaro et al. disclose a method for the selective removal of high-k dielectrics where in claim 2, the required thickness of greater than 1 nm of high-k dielectric is disclosed.

It would have been obvious to one of having ordinary skill in the art at the time the invention was made to include the required surface channel, the required ultra-shallow channel structures, the required metal oxide and the required high-k dielectric thickness in Kim et al. as taught by Currie et al., Sohn et al., Hoffman et al. and Rotondaro et al. in order to have a semiconductor device with increased performance.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Fazli Erdem whose telephone number is (571) 272-1914. The examiner can normally be reached on M - F 8:00 - 5:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nathan Flynn can be reached on (571) 272-1915. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Art Unit: 2826

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

FE

June 25, 2005



NATHAN J. FLYNN
SUPERVISORY PATENT EXAMINER
TECHNOLOGY CENTER 2800